1.9 GHz AGC AMPLIFIER

FEATURES

• FREQUENCY RESPONSE: 800 MHz to 1.9 GHz

NEC

- **SUPPLY VOLTAGE RANGE:** 2.7~3.3 ∨
- VAGC: 0.6~2.3 V
- SUPER SMALL SURFACE MOUNT PACKAGE
- TAPE AND REEL PACKAGING OPTION AVAILABLE
- GAIN CONTROL RANGE UP TO 40 dB

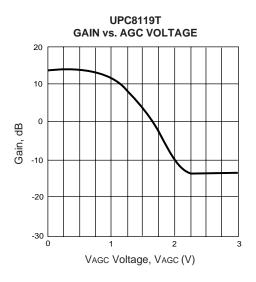
DESCRIPTION

The UPC8119T is a Silicon Monolithic Microwave Integrated Circuit which is manufactured using the NESAT III process. The NESAT III process produces transistors with fT approaching 20 GHz. This device is suitable as an Automatic Gain Control Amplifier stage in cellular radios, GPS receivers, PCN, and test/measurement equipment.

NEC's stringent quality assurance and test procedures assure the highest reliability and performance.

ELECTRICAL CHARACTERISTICS (TA = 25° C, Vcc = 3.0 V, ZS = ZL = 50Ω)

| PART NUMBER PACKAGE OUTLINE | | | | UPC8119T T06 | | |
|--------------------------------|--|-------------------|----------|--------------------|------------------|--|
| SYMBOLS | PARAMETERS AND CONDITIONS | UNITS | MIN | TYP 11 | MAX 15 | |
| Icc | Circuit Current (no signal) | mA | 7.5 | | | |
| GCR | Gain Control ² f = 950 MHz, PIN = -30 dBm f = 1440 MHz, PIN = -30 dBm f = 1900 MHz, PIN = -30 dBm | dB dB dB | 40 35 | 50 45 22 | | |
| Gрмах | $\begin{array}{llllllllllllllllllllllllllllllllllll$ | dB dB dB | 10 10 | 12.5 13 12.5 | 15 16 | |
| P1dB | Output Power at 1 dB compression, f = 950 MHz, Gрмах f = 1440 MHz, Gрмах f = 1900 MHz, Gрмах | dBm dBm dBm | 0 +1 | +3 +4 +3 | | |
| NF | Noise Figure f = 950 MHz, GPмах f = 1440 MHz, GPмах f = 1900 MHz, GPмах | dB dB dB | | 8.5 7.5 7.2 | 11.5 10.5 | |
| RLIN | Input Return Loss f = 950 MHz, Gрмах f = 1440 MHz,Gрмах | dB dB | 3 3 | 6 6 | | |
| ISOL | Isolation f = 950 MHz, GPMAX f = 1440 MHz, GPMAX | dB dB | 27 31 | 32 36 | | |



ABSOLUTE MAXIMUM RATINGS¹ (TA = 25°C)

| SYMBOLS | PARAMETERS | UNITS | RATINGS |
|---------------------------|-----------------------|-------|-------------|
| Vcc Supply Voltage | | V | 3.6 |
| VAGC Gain Control Voltage | | V | 3.6 |
| Тор | Operating Temperature | °C | -40 to +85 |
| Тѕтс | Storage Temperature | °C | -55 to +150 |

Notes:

1. Operation in excess of any one of these conditions may result in permanent damage.

RECOMMENDED OPERATING CONDITIONS

| SYMBOLS | PARAMETERS | UNITS | MIN | TYP | MAX |
|----------------------------|-----------------------|-------|-----|-----|------|
| Vcc | Supply Voltage | V | 2.7 | 3.0 | 3.3 |
| VAGC | Gain Control Voltage | V | 0.6 | - | 2.4 |
| Тор | Operating Temperature | °C | -40 | 25 | +85 |
| PIN | Input Level | dBm | - | - | -181 |
| f Operating Frequency | | MHz | 100 | - | 1900 |
| IAGC AGC Pin Drive Current | | mA | 0.5 | - | - |

Note:

1. Padj \leq -60 dBc @ $\Delta f = \pm 50$ kHz.

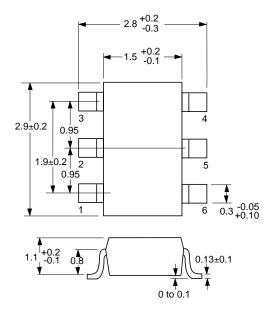
Wave form condition: $\pi/4$ QPSK modulation signal, data rate = 42 kbps, roll off ratio = 0.5, PN9 pattern.

PIN FUNCTIONS

| Pin No. | Symbol | Pin Voltage | Description | Equivalent Circuit |
|---------|--------|--|--|--------------------|
| 1 | IN | _ | RF input pin. Input RF signal with 50 Ω source impedance through a coupling capacitor. External matching circuit is not required. | |
| 2 3 | GND | 0 | Ground pin. This pin must be connected to system ground. Form ground pattern as wide as possible to minimize ground impedance. | |
| 4 | Out | Same as Vcc through external inductor | RF output pin. The output is an open collector with high impedance. External matching circuit is required. | |
| 5 | Vcc | 2.7~3.3 | Supply voltage pin. This pin should be connected with a bypass capacitor (e.g., 1000 pF) to minimize ground impedance. | |
| 6 | Vagc | 0~3.3 | Gain Control pin. The gain slope vs. increasing AGC voltage is summarized below: | 6 |
| | | | Device Gain Slope vs. VAGC UPC8119T Down | |

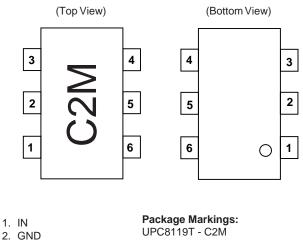
OUTLINE DIMENSIONS (Units in mm)

PACKAGE OUTLINE T06





LEAD CONNECTIONS



- 3. GND
- 4. OUT
- 5. Vcc

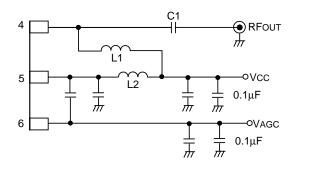
6. VAGC

ORDERING INFORMATION

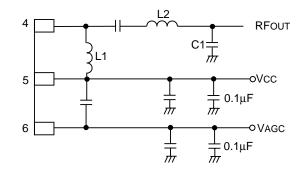
| PART NUMBER | QUANTITY | |
|-------------|----------|--|
| UPC8119T-E3 | 3K/Reel | |

TEST CIRCUIT

900 MHz



1900 MHz



| Fout | L1 | L2 | C1 | Unless Noted |
|------|-------|-----------|-------|----------------------------|
| 900 | 6.8nH | 15nH | 1.5pF | All Other Caps = 1000pF |
| 1900 | 100nH | 5nH (TRL) | 2.2pF | |

Life Support Applications

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